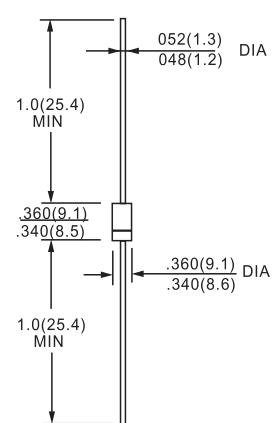


**TAYCHIPST****HIGH EFFICIENCY RECTIFIER****HER601 THRU HER608****50V-1000V 6.0A****FEATURES**

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

MECHANICAL DATA

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 2.1 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- Epoxy: UL 94V-O rate flame retardant



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

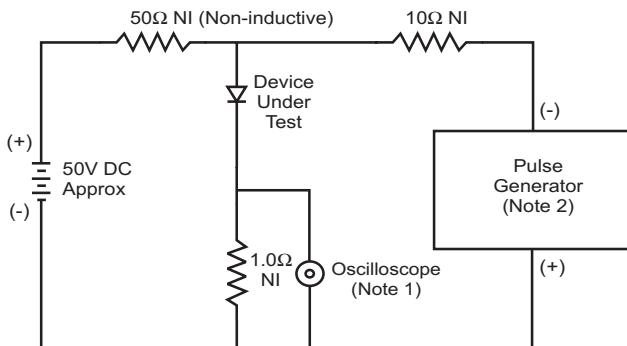
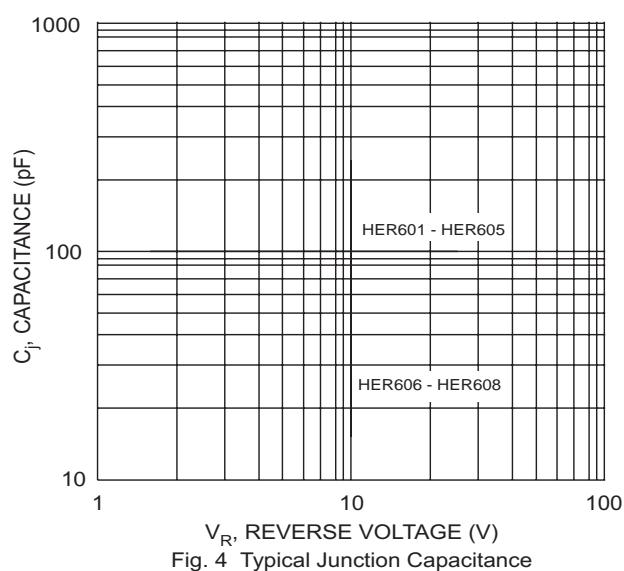
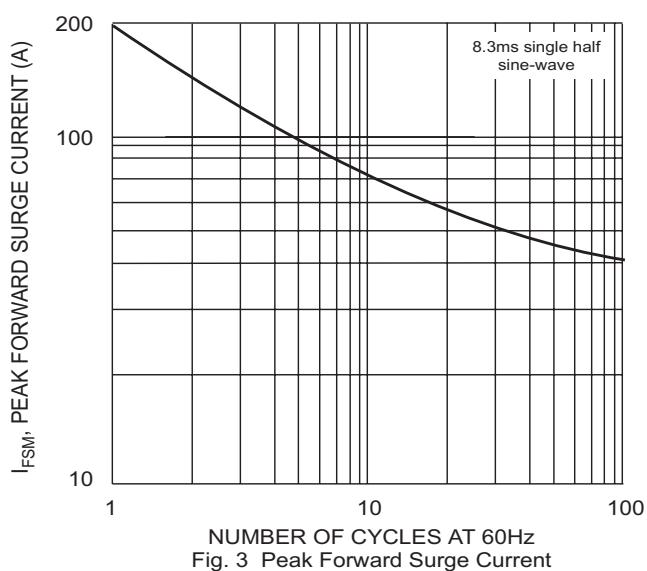
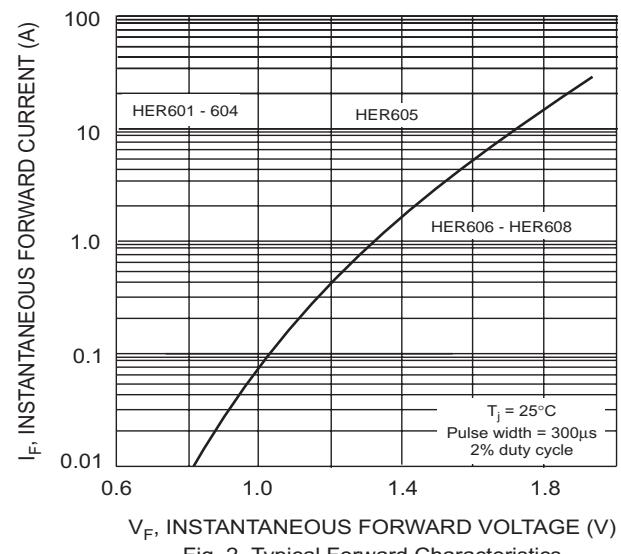
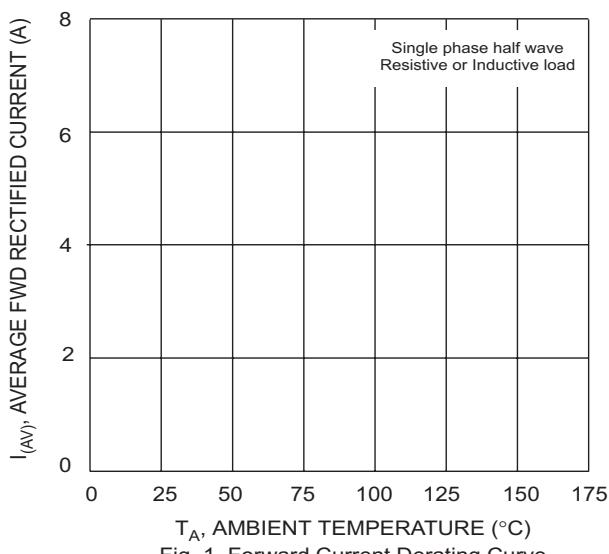
Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

| Characteristic | Symbol | HER 601 | HER 602 | HER 603 | HER 604 | HER 605 | HER 606 | HER 607 | HER 608 | Unit | | | | | |
|---|--|-------------|------------|------------|------------|------------|------------|------------|------------|------|--|--|--|--|--|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | VR _{RRM} VR _{RWM} VR | 50 | 100 | 200 | 300 | 400 | 600 | 800 | 1000 | V | | | | | |
| RMS Reverse Voltage | VR(RMS) | 35 | 70 | 140 | 210 | 280 | 420 | 560 | 700 | V | | | | | |
| Average Rectified Output Current (Note 1) | Io | 6.0 | | | | | | | | A | | | | | |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method) | I _{FSM} | 200 | | | | | | | | A | | | | | |
| Forward Voltage @I _F = 6.0A | V _{FM} | 1.0 | | | 1.3 | 1.7 | | | 1.7 | V | | | | | |
| Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C | I _{RM} | 10.0 100 | | | | | | | | μA | | | | | |
| Reverse Recovery Time (Note 2) | t _{rr} | 50 | | | 75 | | | nS | | | | | | | |
| Typical Junction Capacitance (Note 3) | C _j | 100 | | | 65 | | | pF | | | | | | | |
| Operating Temperature Range | T _j | -65 to +125 | | | | | | | | °C | | | | | |
| Storage Temperature Range | T _{STG} | -65 to +150 | | | | | | | | °C | | | | | |

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

2. Measured with IF = 0.5A, IR = 1.0A, IRR = 0.25A. See figure 5.

3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

**TAYCHIPST****HIGH EFFICIENCY RECTIFIER****HER601 THRU HER608****50V-1000V 6.0A**

Notes:

1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
2. Rise Time = 10ns max. Input Impedance = 50Ω.

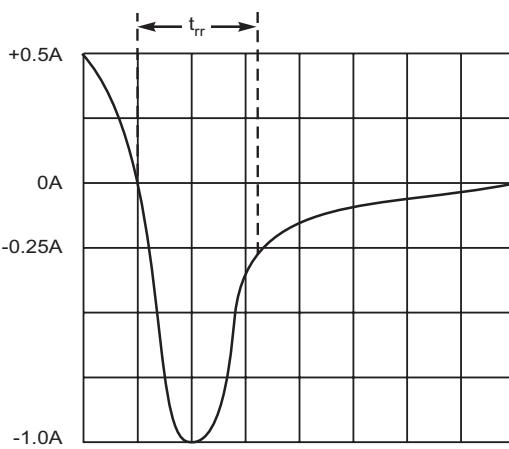


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit